



LOW VOLTAGE TRANSIL™

FEATURES

- UNIDIRECTIONAL TRANSIL DIODE
- PEAK PULSE POWER : 600 W (10/1000μs)
- REVERSE STAND-OFF VOLTAGE = 3.3 V
- LOW CLAMPING FACTOR
- FAST RESPONSE TIME
- UL RECOGNIZED

DESCRIPTION

The SMLVT3V3 is a Transil diode designed specifically for protecting 3.3V supplied sensitive equipment against transient overvoltages.

Transil diodes provide high overvoltage protection by clamping action. Their instantaneous response to transient overvoltages makes them particularly suited to protect voltage sensitive devices such as MOS technology and low voltage supply IC's.



SMB

(JEDEC DO-214AA)

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25^{\circ}\text{C}$)

Symbol	Parameter		Value	Unit
P_{PP}	Peak pulse power dissipation (see note 1)	T_j initial = T_{amb}	600	W
P	Power dissipation on infinite heatsink	$T_{amb} = 75^{\circ}\text{C}$	5	W
I_{FSM}	Non repetitive surge peak forward current	$t_p = 10 \text{ ms}$ T_j initial = T_{amb}	50	A
T_{stg} T_j	Storage temperature range Maximum junction temperature		- 65 to + 175 175	$^{\circ}\text{C}$ $^{\circ}\text{C}$
T_L	Maximum lead temperature for soldering during 10 s		260	$^{\circ}\text{C}$

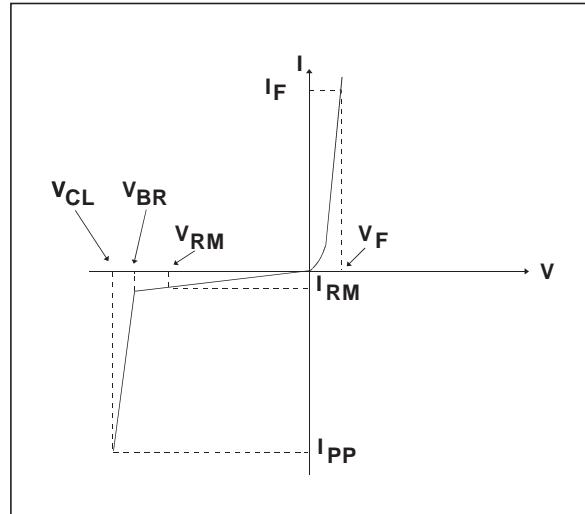
Note 1 : For a surge greater than the maximum values, the diode will fail in short-circuit.

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{th (j-l)}$	Junction to leads	20	$^{\circ}\text{C/W}$
$R_{th (j-a)}$	Junction to ambient on printed circuit on recommended pad layout	100	$^{\circ}\text{C/W}$

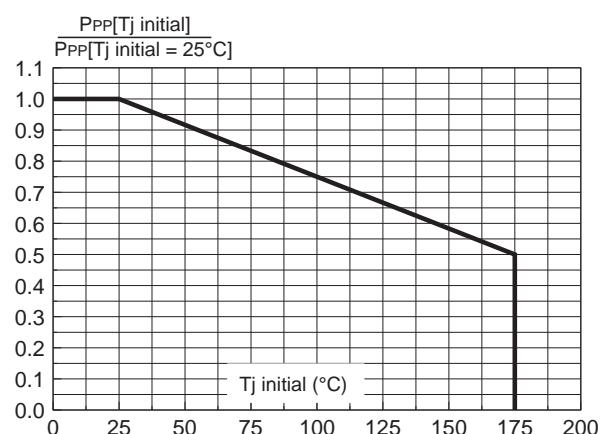
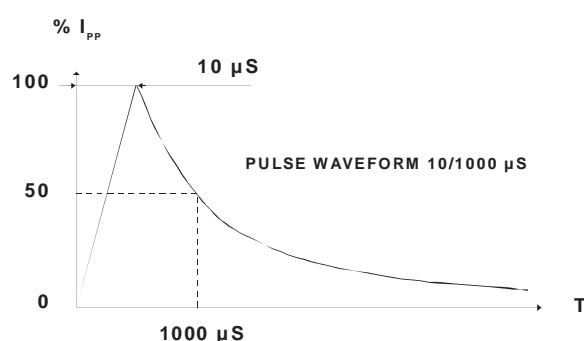
SMLVT3V3**ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^\circ\text{C}$)**

Symbol	Parameter
V_{RM}	Stand-off voltage.
V_{BR}	Breakdown voltage.
V_{CL}	Clamping voltage.
I_{RM}	Leakage current @ V_{RM} .
I_{PP}	Peak pulse current.
αT	Voltage temperature coefficient
V_F	Forward voltage drop



Type	I_{RM} @ V_{RM}		V_{BR} @ I_R		V_{CL} @ I_{PP}		V_{CL} @ I_{PP}		αT max note 3	C max note 4
	max	μA	min	V	max	V	max	A		
SMLVT3V3	200	3.3	4.1	1	7.3	50	10.3	200	-5.3	5200

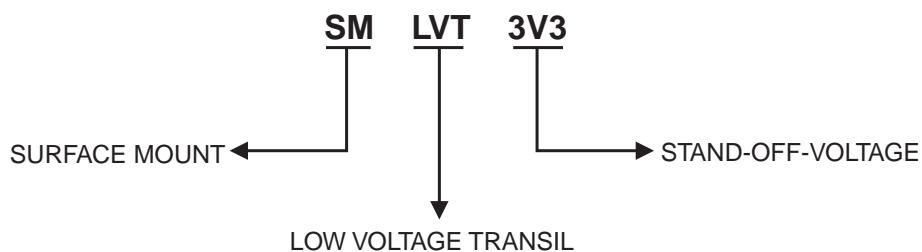
Fig. 1 : Peak pulse power dissipation versus initial junction temperature (printed circuit board).



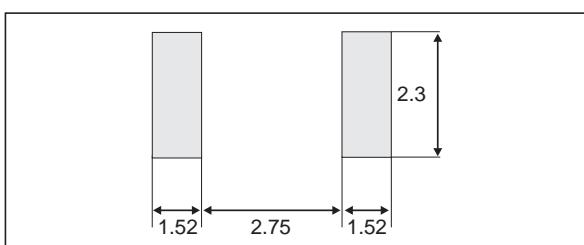
Note 2 : Pulse test : $t_p < 50 \text{ ms}$

Note 3 : $\Delta V_{BR} = \alpha T * (T_{amb} - 25) * V_{BR}(25^\circ\text{C})$.

Note 4 : $V_R = 0\text{V}$, $F = 1\text{MHz}$.

**SMLVT3V3****ORDER CODE****PACKAGE MECHANICAL DATA**
SMB (Plastic) - Jedec DO-214AA

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A1	1.90	2.15	2.45	0.075	0.085	0.096
A2	0.05	0.15	0.20	0.002	0.006	0.008
b	1.95		2.20	0.077		0.087
c	0.15		0.41	0.006		0.016
E	5.10	5.40	5.60	0.201	0.213	0.220
E1	4.05	4.30	4.60	0.159	0.169	0.181
D	3.30	3.60	3.95	0.130	0.142	0.156
L	0.75	1.15	1.60	0.030	0.045	0.063

FOOTPRINT DIMENSIONS (Millimeter)
SMB Plastic.**Marking:** Logo, data code, type code and cathod band**Weight** = 0.12 g**Packaging** : standard packaging is in tape and reel.